

View Online at <https://aerobasegroup.com/nsn/5961-01-157-0362>

Inclosure Material:

Ceramic

Component Name And Quantity:

5 semiconductor device diode

Mounting Method:

Terminal

Voltage Rating In Volts Per Characteristic:

15.0 collector to emitter voltage/static/base open all semiconductor device diode and 20.0 collector to base voltage/static/emitter open all semiconductor device diode and 5.0 emitter to base voltage, static, collector open all semiconductor device diode

Current Rating Per Characteristic:

20.00 milliamperes zero-gate-voltage source current of standard range all semiconductor device diode and 100.00 milliamperes zero-gate-voltage source current blank all semiconductor device diode

Power Rating Per Characteristic:

750.0 milliwatts small-signal input power, common-collector preset all semiconductor

Maximum Operating Temperature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

All semiconductor device diode junction pattern arrangement: pnp

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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